

View Online at <https://aerobasegroup.com/nsn/5961-01-211-0007>

**Inclosure Material:**

Ceramic all transistor

**Overall Length:**

0.975 inches all transistor

**Overall Height:**

0.285 inches all transistor

**Mounting Facility Quantity:**

2 all transistor

**Internal Configuration:**

Junction contact all transistor

**Internal Junction Configuration:**

Npn all transistor

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

2 transistor

**Mounting Method:**

Unthreaded hole all transistor

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

70.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 3.0 breakdown voltage, emitter-to-base, collector open all transistor

**Current Rating Per Characteristic:**

20.00 amperes collector current, dc all transistor

**Power Rating Per Characteristic:**

250.0 watts total device dissipation all transistor

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius junction all transistor

**Terminal Type And Quantity:**

4 ribbon all transistor

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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